NSN 5961-01-318-8810

Diode Semiconductor Device - Page 1 of 1



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End Application:
Mesp
Criticality Code Justification:
Feat
Semiconductor Material:
Silicon
Special Features:
Selected from p/n jantxv1n5532b; jantx1n5532b; fscm 81349; hardness critical item
Nuclear Hardness Critical Feature:
Hardened
Test Data Document:
63812-8856220 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format;
excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental
and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0